Diode Semiconductor Device - Page 1 of 1



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Inclos	sure Material:
Glass	
Overa	all Length:
	linches
	inal Length:
	linches
Overa	all Diameter:
0.107	inches
Joint	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Moun	nting Method:
Termi	inal
Featu	ires Provided:
Herm	etically sealed case
Semi	conductor Material:
Silico	n
Volta	ge Rating In Volts Per Characteristic:
13.0	regulator voltage
Volta	ge Tolerance In Percent:
-20.0/	/+20.0
Curre	ent Rating Per Characteristic:
9.50 r	nilliamperes source cutoff current horsepower metric
Powe	er Rating Per Characteristic:
500.0	milliwatts small-signal input power, common-collector preset
Maxir	num Operating Tempurature Per Measurement Point:
200.0	degrees celsius ambient air
Term	inal Type And Quantity:
3 unir	nsulated wire lead
Shelf	Life:
N/a	
Unit (Of Measure:
Demi	litarization:
No	
Fiig:	
	a0